



Silicon MEMS Timing Solutions

Product Selector 2018



NETWORKING, SERVER, STORAGE & TELECOM



MOBILE, WEARABLE & IOT



INDUSTRIAL & AUTOMOTIVE



CONSUMER

- More features
- Highest performance
- Smallest size
- Lowest power
- Best reliability



GREEN
SOLUTIONS



INSTANT
SAMPLES



LIFETIME
WARRANTY

MEMS Oscillator Product Portfolio



| µPower 32 kHz TCXO 1.2 mm ² | µPower TCXO 1.2 mm ² | Low Power Oscillators | High Temp Oscillators | AEC-Q100 Automotive Oscillators | Spread Spectrum Oscillators | Low Jitter Oscillators | VCXO | TCXO/ VCTCXO/ DCTCXO | DCXO In-System Programmable |
|--------------------------------------------------|------------------------------------------------------------|------------------------------------------------|------------------------------------------------------------|--------------------------------------------------------------------------|-------------------------------------------------|-----------------------------------------------------------------------------|----------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------|---------------------------------------------------------------|
| SiT1552 ±10, 13, 22 ppm | SiT1576* ±5 ppm 1 Hz-2 MHz 2.5 ns Jitter** | SiT1602 3.75-77.76 MHz 3.1-4.9 mA | SiT1618 7.3728-48 MHz -40 to +125°C | SiT8924/5* 1-137 MHz -55 to +125°C | SiT9005* 17 dB Reduction 1-141 MHz | SiT8208/9* 1-220 MHz 0.5 ps Jitter* | SiT3807 1.5-45 MHz | SiT5358/9* <i>Elite Platform</i> 1-220 MHz ±0.05 ppm 0 to +70°C | SiT3907* 1-220 MHz |
| SiT1566/8 ±3, 5 ppm 2.5 ns Jitter** | µPower Oscillators 1.2 mm ² | SiT8008/9* 1-137 MHz 3.1-5.9 mA | SiT8918/9* 1-137 MHz -40 to +125°C | SiT2024/5* 1-137 MHz -55 to +125°C SOT23-5 | SiT9003* Low Power 1-110 MHz | SiT9120 25-212.5 MHz 0.6 ps Jitter** | SiT3808/9* 1-220 MHz | SiT5356/7* <i>Elite Platform</i> 1-220 MHz ±0.1 to 0.25 ppm -40 to +105°C | SiT3521/2* I2C/SPI 1-725 MHz 0.21 ps Jitter** |
| µPower 32 kHz Oscillators | SiT1569* 1 Hz-462.5 kHz ±50 ppm | SiT2001/2* 1-137 MHz SOT23-5 | SiT8920/1* 1-137 MHz -55 to +125°C | SiT9025* 1-150 MHz 30 dB Reduction | SiT9002* 1-220 MHz | SiT9121/2* 1-625 MHz 0.6 ps Jitter** | SiT3372/3* <i>Elite Platform</i> 1-725 MHz ±10 to 50 ppm 0.21 ps Jitter** | SiT5155 <i>Elite Platform</i> 1-40 MHz ±0.5 ppm -40 to +105°C | |
| SiT1532/3 1508 & 2012 | SiT1579* 1 Hz-2 MHz ±50 ppm | | SiT2018/9* 1-137 MHz -40 to +125°C SOT23-5 | SiT9386/7* <i>Elite Platform</i> 1-725 MHz -40 to +105°C | | SiT9365 <i>Elite Platform</i> 25-325 MHz 0.21 ps Jitter** | | SiT5156/7* <i>Elite Platform</i> 1-220 MHz ±0.5 to 2.5 ppm -40 to +105°C | |
| SiT1572 ±50 ppm 1508 | SiT1534 1 Hz-32 kHz 2012 Option | | SiT2020/1* 1-137 MHz -55 to +125°C SOT23-5 | | | SiT9366/7* <i>Elite Platform</i> 1-725 MHz 0.21 ps Jitter** | | SiT5021/2* 1-625 MHz ±5 ppm | |
| SiT1630 -40 to +105°C 2012, SOT23 | SiT8021* 1-26 MHz 60-280 µA | | | | | | | | |

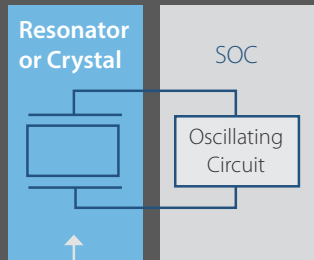
* Any frequency programmable within the frequency range with 6 decimals of accuracy

** Integrated rms phase jitter, see datasheet for integration range

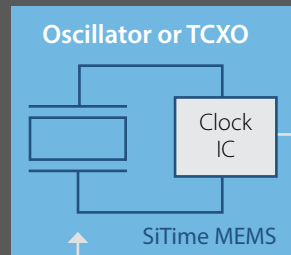
Elite Platform families use DualMEMS™ technology for best dynamic performance

| | | | |
|--|---------------------------------------|--|-------------------------------------------------------------------------------|
| | NanoDrive™ output for lowest power | | Pin-to-pin compatible with quartz devices |
| | LVPECL, LVDS, HCSL output | | Available as field programmable for use with Time Machine II Programmer |
| | LVCMOS output | | |

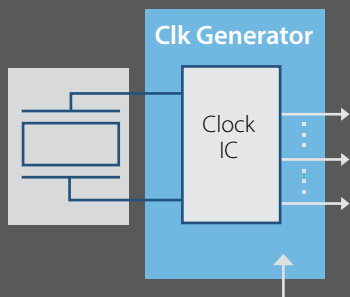
SiTime's Analog Expertise Enables Unique Features



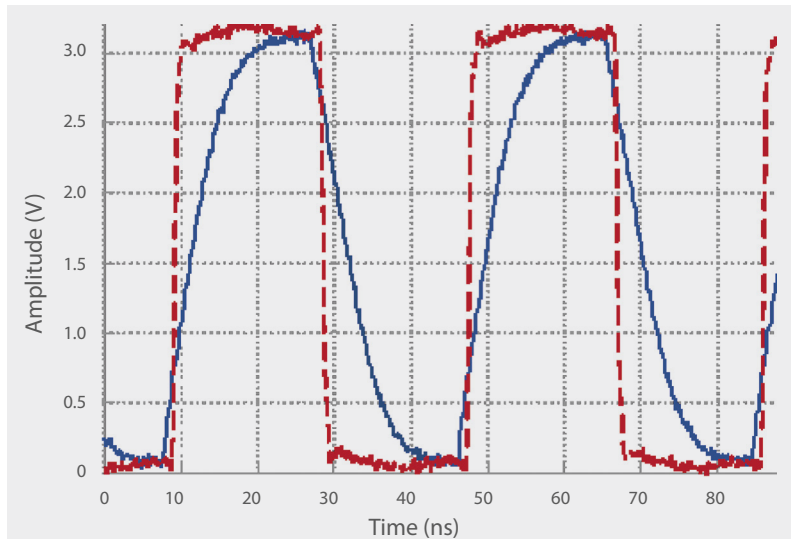
Passive Device
Needs ext. oscillating circuit
2 terminals used



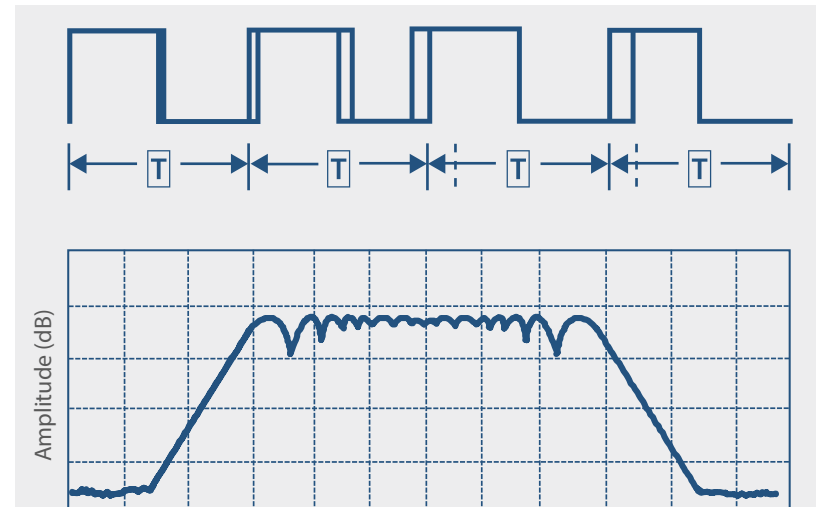
Active Device
2 chips in package
4, 6, 10 terminals



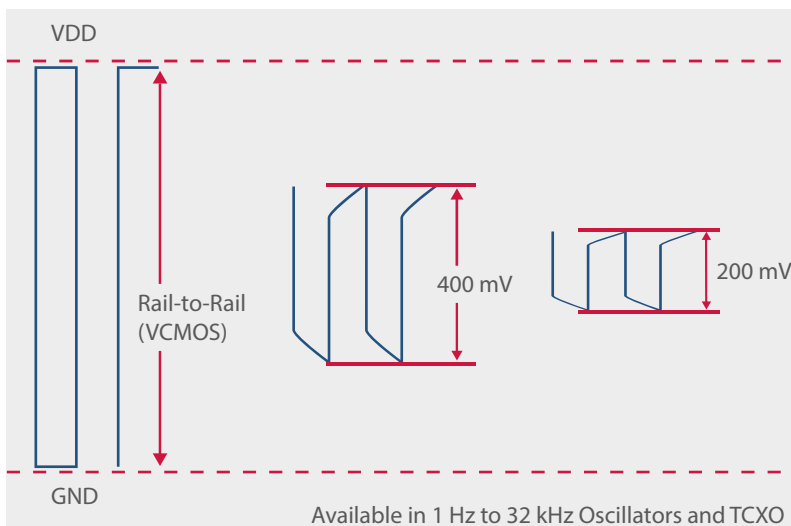
Active IC
Needs ext. clock reference
Many terminals/outputs



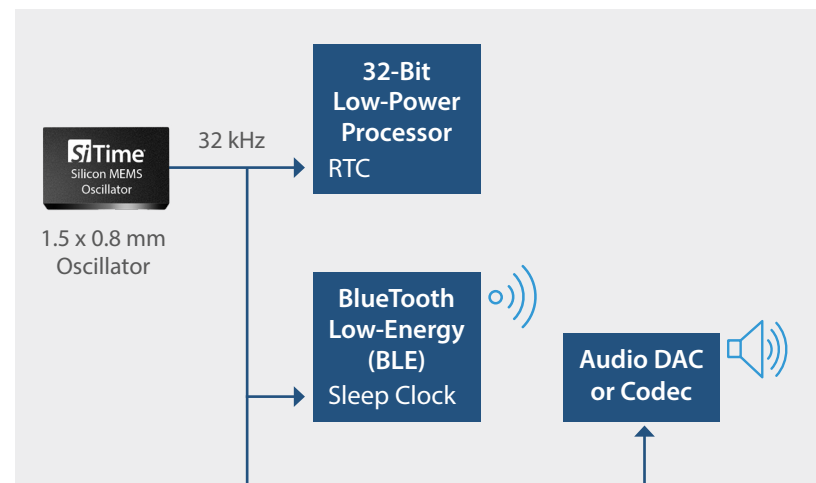
Configurable Rise/Fall Time to Reduce EMI



Spread Spectrum to Reduce EMI



NanoDrive™ Output to Optimize Swing and Lower Power



Drive Multiple Loads to Minimize BOM and Board Space

SiTime oscillators comprise a resonator and oscillator IC in one active device as shown in the middle diagram on the left. As a MEMS and analog company, SiTime has combined man-decades of MEMS expertise with analog CMOS circuit design, resulting in flexible products with the most features and highest performance.

MEMS Oscillator Product Selector



| SiTime Base Part No. | Output Freq. | Frequency Stability (ppm) | Supply Volt. (V) | Supply Current (Typical) | Package | Output Logic | Target Applications | Features |
|----------------------|--------------|---------------------------|------------------|--------------------------|---------|--------------|---------------------|----------|
|----------------------|--------------|---------------------------|------------------|--------------------------|---------|--------------|---------------------|----------|

µPower 32 kHz Oscillators & TCXOs | Replace XTAL, XO, TCXO | Smallest size | Drive two or more loads | Best accuracy (stability) | Best reliability

| | | | | | | | | |
|-----------------------|------------|------------------------------------------------|--------------|---------|---------------|-------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------|
| SiT1532/33 | 32.768 kHz | 75, 100, 250 over temp (10, 20 room temp) | 1.2 to 3.63 | 0.90 µA | 1508, 2012 | NanoDrive, LVCMOS | <ul style="list-style-type: none">• Smart meters• Health & wellness monitors• RTC reference clock• Industrial timekeeping & battery management• Multi-drop 32 kHz clock distribution• Bluetooth & WiFi modules• Internet of Things (IoT), cellular connectivity• Smart utility water, gas & electricity meters (AMR)• Connectivity modules | Smallest XO |
| SiT1572 | | ±50 | 1.62 to 3.63 | 4.5 µA | 1508 | LVCMOS | | Smallest XO |
| SiT1630 | | 75, 100, 150 over temp (20 room temp) | 1.5 to 3.63 | 1.0 µA | 2012, SOT23-5 | LVCMOS | | -40 to +105°C |
| SiT1552 TCXO | | ±10, ±13, ±22, all-inclusive | 1.5 to 3.63 | 0.99 µA | 1508 | NanoDrive, LVCMOS | | Smallest TCXO |
| SiT1566 Super-TCXO | | ±3, ±5, all-inclusive | 1.62 to 3.63 | 4.5 µA | | LVCMOS | | Smallest XO, 2.5 ns rms phase jitter |
| SiT1568 Super-TCXO | | ±5 all-inclusive (after overmold/underfill) | 1.8 | | | | | |

µPower Oscillators & TCXOs | Smallest size | Lowest power | Lightest weight | Drive two or more loads | Best accuracy (stability) | Best reliability

| | | | | | | | | |
|-----------------------|--------------------|------------------------------------------|-----------------|-------------------------------|------------|-------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------|
| SiT1534 | 1 Hz to 32.768 kHz | 75, 100, 250 over temp (20 room temp) | 1.2 to 3.63 | 0.90 µA | 1508, 2012 | NanoDrive, LVCMOS | <ul style="list-style-type: none">• Health & wellness monitors• Industrial data loggers & sensor interface• IoT beacons• Smart pens <ul style="list-style-type: none">• Wearables & IoT• Portable audio <ul style="list-style-type: none">• Industrial & medical sensors | Smallest XO |
| SiT1569 | 1 Hz to 462.5 kHz | ±50 | 1.62 to 3.63 | 2.0 µA (100 kHz) | 1508 | LVCMOS | | Smallest XO, 2.5 ns rms phase jitter |
| SiT1576 Super-TCXO | 1 Hz to 2.5 MHz | ±5 all inclusive | 1.62 to 3.63 | 8.0 µA (100 kHz) | | | | |
| SiT1579 | 1 Hz to 2.5 MHz | ±50 | 1.62 to 3.63 | 8.0 µA (100 kHz) | | | | |
| SiT8021 | 1 MHz to 26 MHz | ±100 | 1.8, 2.5 to 3.3 | 60 to 280 µA (0.7 µA stby) | | | | |

Low-Power Oscillators | Best reliability | Pin-compatible QFN or SOT-23 package for best solder-joint reliability

| | | | | | | | | |
|------------|-------------------|---------------|-----------------|--------------------------------------|---------------------------------|---------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|
| SiT1602 | 52 standard freq. | ±20, ±25, ±50 | 1.8, 2.5 to 3.3 | 3.1 to 5.5 mA (0.6 - 1.0 µA stby) | 2016, 2520, 3225, 5032, 7050 | LVC MOS | <ul style="list-style-type: none">• Consumer, industrial and audio video equipment• Networking, storage & servers• Industrial sensors, PLC & motor server• Microprocessor & FPGA clocking | FP* |
| SiT8008/09 | 1 MHz to 137 MHz | | | 3.6 to 5.4 mA (1.0 µA stby) | SOT23-5 | LVC MOS | | |
| SiT2001/02 | 1 MHz to 137 MHz | | | | | | | |

Low-Jitter Oscillators | 0.1 ppb/g (g-sensitivity, vibration immunity) | Best reliability

| | | | | | | | | |
|--------------|-------------------|--------------------|------------|-------------|------------------|--------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------|
| SiT9365** | 32 standard freq. | ±10, ±20, ±25, ±50 | 2.5 to 3.3 | 76 to 89 mA | 3225, 5032, 7050 | LVPECL, LVDS, HCSL | <ul style="list-style-type: none">• Computing• Networking, storage, servers, & telecom• Optical modules• Industrial control• Instrumentation• FPGA clocking | 0.21 ps rms phase jitter |
| SiT9366/67** | 1 MHz to 725 MHz | | | | | | | |
| SiT9120 | 31 standard freq. | | 2.5 to 3.3 | 54 to 69 mA | 3225, 5032, 7050 | LVPECL, LVDS | | 0.5/0.6 ps rms phase jitter, FP* |
| SiT9121/22 | 1 MHz to 625 MHz | | | | | | | |
| SiT8208/09 | 1 MHz to 220 MHz | | | | | | | |

| SiTime Base Part No. | Output Freq. | Frequency Stability (ppm) | Supply Volt. (V) | Supply Current (Typical) | Package | Output Logic | Target Applications | Features |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|---------------------------|------------------------------------|--------------------------------|-------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| High-Temperature and Automotive Oscillators 0.1 ppb/g (g-sensitivity, vibration immunity) Best reliability Pin-compatible QFN or SOT-23 package for best solder-joint reliability | | | | | | | | |
| SiT1618 | 33 standard freq. | ±20, ±25, ±30, ±50 | 1.8, 2.5 to 3.3 | 3.6 to 5.4 mA (1.0 µA stby) | 2016, 2520, 3225, 5032, 7050 | LVCMOS | <ul style="list-style-type: none">High-temp industrial equipment such as industrial control systems & industrial sensorsServo motor, PLC & high-temp networking gearsOutdoor systems (medical & health monitoring)Asset tracking systems | FP*, -40 to +125°C |
| SiT8918/19 | 1 MHz to 137 MHz | | | | SOT23-5 | | | |
| SiT2018/19 | | | | | | | | |
| SiT8920/21 | 1 MHz to 137 MHz | | | | 2016, 2520, 3225, 5032, 7050 | LVCMOS | | <ul style="list-style-type: none">Ruggedized applications in harsh environmentsApplications in extreme temperature conditionsAvionics equipment |
| SiT2020/21 | | | | SOT23-5 | | | | |
| SiT8924/25 | 1 MHz to 137 MHz | | | 2016, 2520, 3225, 5032, 7050 | LVCMOS | <ul style="list-style-type: none">AEC-Q100 automotive applicationsADAS, camera modules, Radar & LidarAutomotive EthernetInfotainmentLED headlightsECUs (engine & transmission control units) | | |
| SiT2024/25 | 1 MHz to 137 MHz | | | SOT23-5 | | | | |
| SiT9025 | 1 MHz to 150 MHz | ±25, ±50 | 0.6 to 7.9 mA (0.7 to 2.6 µA stby) | 2016, 2520, 3225 | LVPECL, LVDS, HCSL | | EMI reduction, -55 to +125°C | |
| SiT9386/87** | 1 MHz to 725 MHz | ±20, ±25, ±50 | | | | | 2.5, 2.8, 3.0, 3.3 | 70 to 89 mA |
| VCXO (Voltage Controlled Oscillators) ±25 to ±3200 ppm pull range, <1% linearity 0.1 ppb/g (g-sensitivity, vibration immunity) Best reliability | | | | | | | | |
| SiT3372/73** | 1 MHz to 725 MHz | ±15, ±25, ±30, ±50 | 2.5 to 3.3 | 76 to 92 mA | 3225, 5032, 7050 | LVPECL, LVDS, HCSL | <ul style="list-style-type: none">Audio/videoWireless & telecom equipmentInstrumentation | 0.21 ps rms phase jitter |
| SiT3807 | 31 standard freq. | ±10, ±25, ±50 | 1.8, 2.5 to 3.3 | 29 to 34 mA (10 to 70 µA stby) | 2520, 3225, 5032, 7050 | LVCMOS | | 0.5 ps rms phase jitter, FP* |
| SiT3808/09 | 1 MHz to 220 MHz | | | | | | | |
| TCXO/VCTCXO/DCTCXO ±6.25 to ±3200 ppm pull range 5 ppt resolution frequency control 0.1 ppb/g (g-sensitivity, vibration immunity) Best reliability | | | | | | | | |
| SiT5358/59 Super-TCXO** | 1 MHz to 220 MHz | ±0.05 | 2.5, 2.8, 3.0, 3.3 | 40 to 45 mA | 5032 | LVCMOS, Clipped Sinewave | <ul style="list-style-type: none">High-reliability telecom & networkingBroadband satellite, Industrial, test & instrumentation | I2C, 1 ppb/°C slope, 0 to +70°C |
| SiT5356/57 Super-TCXO** | | ±0.1, ±0.2, ±0.25 | | | | | | I2C programmable, 1 ppb/°C slope, -40 to +105°C |
| SiT5155 Super-TCXO** | 13 standard freq. | ±0.5, ±1, ±2.5 | | | | | <ul style="list-style-type: none">High-reliability networking, server, storage, & telecomIndustrial/automotive/telecom GNSS | |
| SiT5156/57 Super-TCXO** | 1 MHz to 220 MHz | | | | | | | |
| SiT5021/22 | 1 MHz to 625 MHz | ±5 | 2.5, 3.3, 2.25 to 3.63 | 55 to 69 mA | 3225, 5032, 7050 | LVPECL, LVDS | <ul style="list-style-type: none">Instrumentation & networkingEmbedded systems | 0.6 ps rms phase jitter |
| DCXO (In-System Programmable) Digital pull for lowest noise Up to ±3200 ppm pull range, 5 ppt pull resolution, <1% linearity | | | | | | | | |
| SiT3521/22** | 1 MHz to 725 MHz | ±20, ±25, ±50 | 2.5 to 3.3 | 70 to 82 mA | 5032 | LVPECL, LVDS, HCSL | <ul style="list-style-type: none">Communication & broadcastingTest & measurement equipment | I2C programmable, 0.21 ps rms phase jitter |
| SiT3907 | 1 MHz to 220 MHz | ±10, ±25, ±50 | 1.8, 2.5, 2.8, 3.3 | 32 mA | 3225, 5032, 7050 | LVCMOS | <ul style="list-style-type: none">Instrumentation & audio/videoPhase locked loops (PLL) & FPGA data recovery | 0.5 ps rms phase jitter, FP* |
| SSXO (Spread Spectrum Oscillators) ±0.125 to ±2.0% center spread, -0.25% to -4.0% down spread, Lowest cycle-cycle jitter | | | | | | | | |
| SiT9005 | 1 MHz to 141 MHz | ±20, ±25, ±50 | 1.8, 2.5 to 3.3 | 4.0 to 5.6 mA | 2016, 2520, 3225 (SiT9003 for 5032, 7050) | LVCMOS | <ul style="list-style-type: none">Printers & flat panelsIP camerasPCI ExpressMicroprocessors | Smallest SSXO, FP* |
| SiT9002 | 1 MHz to 220 MHz | ±25, ±50 | 1.8, 2.5, 3.3 | 48 to 75 mA | 5032, 7050 | LVPECL, CML, LVDS, HCSL | | FP* |

All families have programmable frequency within the output frequency range with 6 decimals of accuracy, except 32.768 kHz products and those indicated as having standard frequencies. All families are available in -40 to +85°C unless otherwise noted.
 *Field programmable with Time Machine II Programmer
 **Elite Platform products with DualMEMS™ technology for best dynamic performance

Application Examples and Benefits



| Segment | Application | SiTime Benefits | SiTime Oscillator Family |
|----------------------------------------|---------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------|
| Networking, Servers, Storage & Telecom | 4G/5G RRH, small cells, macro cells, microwave backhaul, other RF systems | Best dynamic stability 1ppb/°C, resistant to airflow and rapid thermal transients Most robust against shock/vibration, no activity dips | SiT5356/57/58/59, SiT5155/56/57 |
| | Carrier-grade routers & switches, SyncE, IEEE 1588 | Best dynamic stability 1ppb/°C, resistant to airflow and rapid thermal transients Best resilience (EMI susceptibility, PSRR), no activity dips | SiT5356/57/58/59, SiT9121/22, SiT9365/66/67 |
| | Servers, storage, SATA, SAN, PCIe, Fibre channel | ±10 to 25 ppm stability over industrial temperature Best resilience (EMI susceptibility, PSRR) | SiT9120, SiT9365/66/67, SiT8008 |
| | 100/200/400G ONT, SFP & optical modules | Smallest package (3.2 x 2.5 mm) for LVPECL/LVDS Best dynamic stability, no activity dips | SiT9365/66/67, SiT5356/57/58/59 |
| | G.fast, DOCSIS 3.1, cable modems | High frequencies with 6 digits of accuracy Best PSRR, shock/vibration resistance | SiT5356/57/58/59, SiT3521/22, SiT9365/66/67 |
| Automotive | ADAS and around view cameras | Smallest package (2.0 x 1.6 mm) EMI reduction up to 17 dB | SiT8924/25, SiT9025 |
| | ADAS computer, connected car | Ultra-low jitter under harsh condition (0.215 ps) Best stability under high temperature (±20 ppm at 105°C) | SiT9386/87 |
| | Infotainment | Reliable startup at -40°C EMI reduction up to 17 dB | SiT8924/25, SiT9025 |
| | LED headlights | Best stability under high temperature Best EMI control | SiT8924/25 |
| | Wireless charger | Programmability for short lead times, even for custom frequencies | SiT8924/25 |
| | Post-solder optical inspection | SOT23 leaded (not QFN) package ensures easy post-solder optical inspection | SiT2024/25 |
| Industrial | Precision GNSS | Best location accuracy under shock, vibration, rapid thermal transients, & EMI | SiT5155/56/57, SiT5356/57/58/59 |
| | Multi-function printers | Reduce EMI in system Customizable frequencies with 6 digits of accuracy | SiT9002/03/05, SiT8008 |
| | IP camera, security/CCTV system, VoIP camera | Smallest packages (2.0 x 1.6 mm, 2.5 x 2.0 mm) Best resilience (shock, vibration, EMS immunity) Customizable frequencies with 6 digits of accuracy | SiT8008, SiT1602 |
| | FPGA subsystem | Customizable frequencies with 6 digits of accuracy | SiT8008/09, SiT9121/22 |
| | Industrial computers, PLCs, motor control | Best stability under high temperature (+125°C) 30 times better reliability, best resilience | SiT2018/19/20, SiT8008 |
| Mobile, Wearables, & IoT | Activity tracker, smartwatch | 80% smaller than quartz Drive 2 to 3 loads with one chip | SiT1532, SiT1566/68/69, SiT1572 |
| | Activity tracker, smartwatch | 20 to 40% longer battery life Most accurate time reference | SiT1552, SiT1569, SiT1572 |
| | Activity tracker, smartwatch, IoT | Up to 3 times faster startup than quartz (0.5s vs. 1.5s for quartz) | SiT1532/52, SiT1569, SiT1579 |
| | Bluetooth headset | Best resilience (shock, vibration, EMS immunity) | SiT1532/52, SiT1566/68/69 |
| | Medical electronics | Most accurate 32 kHz for time-stamping 80% smaller than quartz | SiT1552, SiT1566/68/69 |
| Consumer | DSC, DVR, DSLR, IP camera, 100M to 10G Ethernet | Smallest package (2.0 x 1.6 mm) ±20 ppm stability over industrial temperature | SiT8008, SiT1602 |
| | Wearables, health monitors, mobile phones, ultra-small notebook PCs | Drive 32 kHz to multiple loads with one chip | SiT1532/33, SiT1566/68/69, SiT1572/76/79 |